



JST131N2-800E 1A TRIAC

Rev.A.1.1

D

ELECTRICAL CHARACTERISTICS ($T_j=25$ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	$V_D=12V$ $R_L=33\Omega$	- -	MAX.	10	mA
				25	
V_{GT}		ALL	MAX.	1.3	V
V_{GD}	$V_D=V_{DRM}$ $T_j=125$ $R_L=3.3k\Omega$	ALL	MIN.	0.2	V
I_L	$I_G=1.2I_{GT}$	- -	MAX.	15	mA
				30	
I_H	$I_T=50mA$		MAX.	15	mA
dV/dt	$V_D=540V$ Gate Open $T_j=110$		MIN.	200	V/ μs
$(dV/dt)_c$	$(dI/dt)_c=0.44A/ms$, $T_j=110$		MIN.	6	V/ μs
t_{on}	$I_G=40mA$ $I_A=200mA$ I_R				

FIG.1: Mosfet on-state current versus case temperature

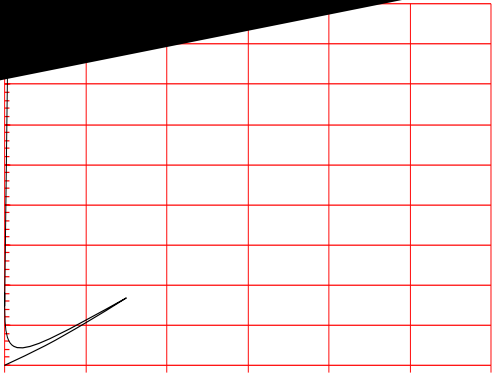
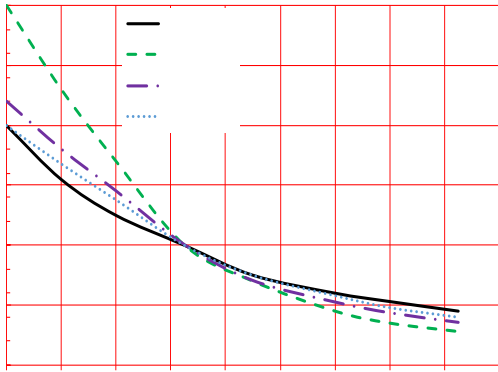


FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature



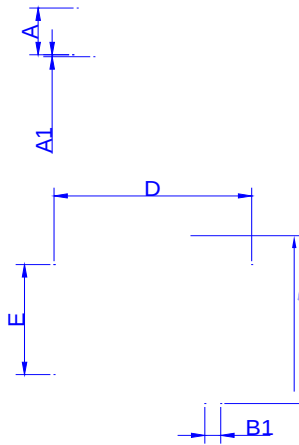
ORDERING INFORMATION

Order code	Voltage $V_{\text{DRM}}/V_{\text{RRM}}$ (V)	IGT(mA)		Package	Base qty. (pcs)	Delivery mode
		- -				
JST131N2-800E	800	10	25	SOT-89-2L	4,000	Tape & Reel

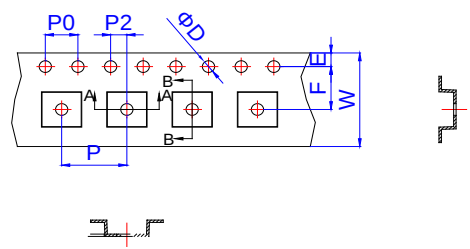
Document Revision History

Date	Revision	Changes
Apr.14, 2023 Oct.16, 2025	A.1.0	Last updated

PACKAGE MECHANICAL DATA



DELIVERY MODE



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
E	1.65	1.75	1.85	0.065	0.069	0.073
F	5.45	5.50	5.55	0.215	0.217	0.219
P2	1.90	2.00	2.10	0.075	0.079	0.082
D	-	1.50	1.60	-	0.059	0.063
D1	1.50			0.059		
P0	3.90	4.00	4.10	0.154	0.157	0.161
10P0	39.80	40.00	40.20	1.567	1.575	1.583
W			12.30			0.482
P	7.90	8.00	8.10	0.311	0.315	0.319
A0	5.20	5.30	5.40	0.204	0.208	0.212
B0	4.80	4.90	5.00	0.188	0.192	0.196
K0	1.75	1.85	1.95	0.069	0.073	0.076
t	0.20	0.25	0.30	0.008	0.010	0.012
θ	3°		5°	3°		5°

